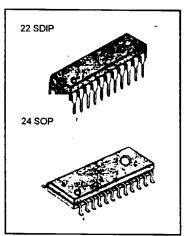


BALLAST CONTROL IC

The KA7531X is a ballast control IC improving power-factor.t The following is the features incorporated in it. It includes PFC control block so that the power-factor can be over 0.99 % and the high voltage at lamp driving block can be maintained constantly. Besides, it prevents the inrush current of lamp discharge and the sputtering. The 3-step soft start function allows lengthen lamp use. The dimming control function is also incorporated to regulate lamp's luminance depending on the intensity of surrounding illumination. The over-current protection, over-heating protection of power switch in driving systems and non-load protection functions are also available.



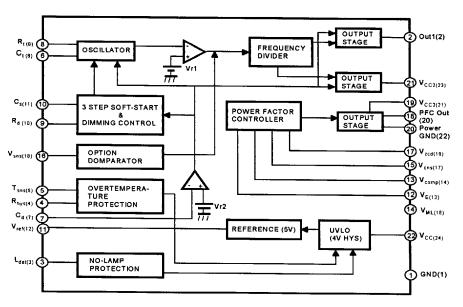
FEATURES

- Power Factor Correction
- Dimming control
- 3 Step Soft start
- ZVS Driving
- Non Lamp Protection
- Protection (OCP, OTP)

BLOCK DIAGRAM

	Device	Package	Operating Temperature
	KA7531	22 SDIP	25 . 400 %
i	KA7531D	24 SOP	-25 ~ + 100 ℃

ORDERING INFORMATION



()IS 24SOP PIN NO

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Page:1 (KA7531)

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Supply Voltage	Vcc	17	v
Peak driver output current	I _{O(P)}	500	mA
Operating ambient temperatute	TOPR	-25 ~ +100	τ
Storage temperature	T _{STG}	-65 ~ +150	r r

ELECTRICAL CHARACTERISTICS

(V_{cc} = 12V, T_A = 25 $^{\circ}$ C, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Мах	Unit
Under Voltage Lock Out Sect	ion				I	
Start Threshold Voltage	Vst		10	10.8	11.6	V
UVLO Hysteresis	V _{THS}		2.8	3.2	3.6	v
Start-Up Supply Current	I _{ST}	V _{cc} = 9V	0.6		1.4	mA
Operating Supply Current	lcc	V _{cc} = 14V, No Load	8		14	mA
Reference section		· · · · · · · · · · · · · · · · · · ·	•			
Reference Voltage	VREF		5.0	5.1	5.2	v
Load Regulation		0 < I _{REF} < 5mA		5	20	mV
Preheating Section	I		I	L	L., , ,	
Preheating Frequency	FP	V _{cs} = 0V, R _t = 33K, C _t = 330pF	120		160	KHz
Preheating Time Current	l _P	V _{CS} = 0V	7		27	μA
Preheating Dead Time	T _{PD}		2		4	μΑ
Oscillator Section			L	L	1	
Amplitude	V _(OSC)		3.0		3.8	v
Normal Frequency	F _N		80	<u> </u>	120	KHz
Normal Dead Time	T _{ND}	V _{CS} = 2V	1.7	1	3.7	μs

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ELECTRICAL CHARACTERISTICS

(V_{cc} = 12V, T_A = 25 °C, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Мах	Unit
3-step Frequency Section		• •		I		1
Preheating Voltage Range	V _{PR}	R _{DC} = 120K, V _{DS} = 1.75V	0.7		1.3	V
Soft start Voltage Ramge	V _{st}	R _{DC} = 120K, V _{DS} = 1.75V	1.3	<u> </u>	1.9	v
Fullpower Voltage Range	VFR	R _{DC} = 120K, V _{DS} = 1.75V	2.8		3.4	v
Dimming Voltage Range	VDR	R _{DC} = 120K, V _{DS} = 1.75V	3.5		4.1	v
Oscillator Section						
Dimming 50 % Frequency	FDIM	R _{DC} = 120K, V _{DS} = 1.75V	100		140	KHz
Dimming Current	1 _{DIM}	R ₀ = 120k Ω				μΑ
Output Section for Ballast Cont	trol Part			4		
Rising Time (NOTE 2)	T _R	No Load		80	120	ns
Falling Time (NOTE 2)	TF	No Load		20	60	пв
High Voltage	V _{OH}	l _o = 30mA	7	8		v
Low Voltage	Vol	l _o = 30mA		0.1	0.4	v
Over Temperature Protection				•		•
High Temperature Voltage	V _{HT}		0.7		1.3	V
Reset Temperature Voltage	V _{RT}		2.1		2.9	v
Hysteresis Max Current	IHYS	R _{HYS} = 50K	80		120	μΑ
Option Comparator						<u> </u>
Option Comparator Voltage	VOPT		2.4		3.2	v
No Lamp Protection						1
No Lamp Protection Voltage	V _{NL}		1.2		1.7	V
Error Amplifier Section				•		
input Offset Voltage (NOTE 2)	VIOL		-1.5	1	15	m∨
Input Bias Current	IIBIAS		-1	-0.1	1	μΑ

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ELECTRICAL CHARACTERISTICS

(V_{CC} = 12V, T_A = 25 $^\circ\!\!\mathrm{C}$, unless otherwise specified)

Characteristic		Symbol	Test Conditions	Min	Тур	Max	Unit
Error Amplifier	Section		.	I			
Large Signal Openloop Voltag	e Gain (NOTE2)	GV1		60	100		dB
Output Current	Source	ISOURCE		2			mA
Output Current	Sink	ISINK				-2	mA
Output Voltage	Low	VLO				1.2	v
Range	High	V _{HI}		4			v
Unity-gain Bandwidth (NOTE2)		UBW			1.0		MHz
Phase Margin (NOTE2)		MPH			57		
Multiplier Section	on			•			
M1 Input Voltage Range (NOTE2)		V _{I(M1)}		0		2	v
M2 Input Voltage Range (NOTE2)		V _{1(M2)}		V _{REF} 2		<u>V_{REF} +1</u> 2	v
Input Bias Curre	nt	IBIAS2		-2		2	μA
Multiplier Gain (I	NOTE2)	GV2	VM1 = 0.5V, VM2 = 3.0V		0.8		V
Current-Sense	Section		•				
Input Offset Volta	age (NOTE2)	Vios		-10		10	mV
Input bias Current		BIASS	$0V \le V_{CS} \le 1.7V$	-5	2	5	μA
Delay to Output (NOTE2)		td(s)		1	200	500	ns
Zero-Current-De	tect Section		• ··· · · · · · · · · · · · · · · · · ·				 _
Input Voltage thr	eshold	V _{TH2}		1.2		1.8	v
Hysteresis		V _{HYS2}		-	200		mV
Input Low Clamp	Voltage	VIC(L)	I _{DET} = -100 μ A	1		0.95	v
Input High Clam	o Voltage	VIC(H)	I _{DET} = 3mA	6.1	7.12		v

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ELECTRICAL CHARACTERISTICS

(V_{cc} = 12V, T_A = 25 $^{\circ}$ C, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
Zero-Current-Detect Section						
Input Current	կ	$0.9 \le V_{DET} \le 6V$		± 5		μA
Input High/Low		V _{DET} < 0.9V			-3	
Clamp Diode Current	lcd	V _{DET} > 6V	+3			mA
Output Section for PFC part						
Rising time (NOTE1)	T _{R2}	No Load		100	120	ns
Falling time (NOTE2)	T _{R2}	No Load		90	110	ns
High Voltage	V _{OH2}		7	9		v
Phase Margin	V _{OL2}			0.2	1.5	V
Self - Starting Section						
Self - Starting Time (NOTE2)	T _{ss}		12			μs
Delay Timer Section		· ·				
Delay Timer Current	ICD		6		14	μΑ
Delay Timer Voltage	V _{CD}		2.5		3.5	V

NOTE1. V_{CC} ought to set up 10V after threshold voltage approve. NOTE2. GV2 = Vo(M)/ { VM1 $\,\times\,$ (VM2 - Vref/2) }

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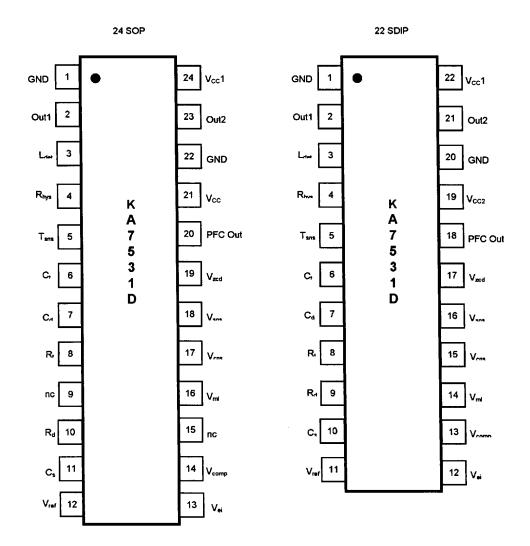
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KA7531 Industrial

PIN CONNECTION (top view)

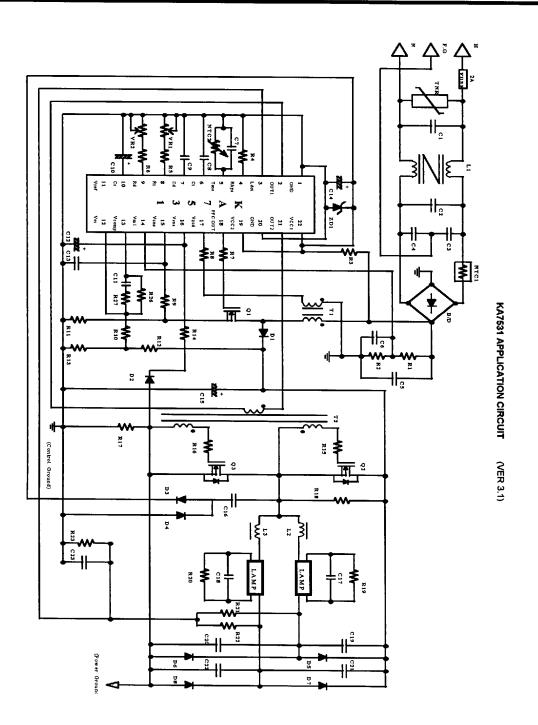


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ELECTRONICS



PARTS LIST (KA7531/D)

Part	Value	Part	Valu	ie	Part	Value
R1	1.8K Ω 1/2W	R30	1ΚΩ		NTC2	KTD-350
R2	10KΩ 1/2W	VR1	500K Ω			
R3	100K Ω 1/2W					
R4	51ΚΩ	C1	0.1 μ F	250V		
R5	33ΚΩ	C2	0.1 µ F	250V	D1	1N4937
R6	240K Ω 1/2W	СЗ	4700pF	250V	D2	1N4937
R7	10 Ω 1/2W	C4	4700pF	250V	D3	15V 1W
R8	27 Ω	C5	563	600V	D4	1N4937
R9	22ΚΩ	C6	103	40V	D5	1N4937
R10	330 Ω	C7	104	16V	D6	6.2V 0.5W
R11	1KΩ 1/2W	C8	331	10V	D7	1N4937
R12	6.2K Ω 1/2W	C9	103	10V	D8	1N4937
R13	1 50K Ω	C10	10 µ F	16V	D9	1N4937
R14	0.5 Ω 1W	C11	104	16V	D10	1N4937
R15	51 Ω					
R16	680 Ω	C13	332	10V	Q1	IRF830
R17	51 Ω	C14	100 µ F	25V	Q2	IRF830
R18	680 Ω	C15	47 μ F	450V	Q3	IRF830
R19	1M Ω	C16	152	630V		
R20	1ΜΩ	C17	562	1000V		
R21	1ΜΩ	C18	562	1000V	L1	BSF-2125
R22	1M Ω	C19	103	630V	T1	EE1619
R23	2ΜΩ	C20	103	630V	T2,T3,T4	El25
R24	2Μ Ω	C21	1μF	10V		
R25	0.5 Ω 1W	C22	22 µ F	16V		
R26	620Κ Ω	C23	103	630V		B/D
R27	20Κ Ω	C24	103	630V	IC	KA7531D
R28	430 Ω	TNR	12G471K			
R29	100 Ω 1W	NTC1	10D-11		FUSE	250V/2A

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Pin Functions

Symbol	Nur	nber	
Symbol	SOP	SDIP	Functions
OUT 1	2	2	Output Pin. It drives powe switching eleements.
OUT 2	23	21	Its output frequency(fo) varies from 50 [Khz] \pm 30 [Khz]. The output voltage level is V _{cc} .
GND	1	1	
GND	22	20	IC Ground
Ldet	3	3	Non Lamp Detect
R _{HYS}	22	20	Over Temkperature Hysteresis Resistor
GND	1	1	It determines the frequency of internal triangular wave generation
GND	22	20	circuit, and then fixed frequency determines output frequency at Out1 and Out2
LDET	3	3	It performs Dimming Control whech regulates lamp intensity.
R _{HYS}	4	4	Delay Timer Capacitor
Cs	11	10	It determines soft-start period during first lamp fire starting. $C = i \frac{dt}{dv}$ (I = 20 μ A, dv = 0.7V, dt = 2.4sec)
VEI	13	12	Error AMP. Input
V _{M1}	16	14	V _{DD} Voltage Multiplier Input
VCOMP	14	13	Error AMP. Output
VREF	12	11	5V Reference
V _{CNS}	17	15	Current Sense for PFC
V _{SNS}	18	16	Voltage Sense
VzcD	19	17	Zero Current Detect
LDET	20	18	Power Factor MOSFET Drive output
T _{SNS}	5	5	Temperature Sense it will be protected with 0.9V below
V _{CC1}	24	22	Vcc
V _{CC2}	21	19	¥CC

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1. SYSTEM SUMMARY

This application note is about functions and designs of electronic ballast, which can drive fluorescent lamp ($32w^2$) by using a KA7531 (ballast control IC)

1) Excellent power saving capability

- Power Factor Correction
- Dimming Control

2) Stable strike and life extention of fluorescent lamp

3 - Step Soft-start
Double Hot Spot generation

3) EMI / RFI and minimize radition noise

Zero voltage switching (ZVS)

4) Minimize eye-strain

- Soft Ignition
- Stable Lighting Output

5) Improvement of system reliability

- No load protection
- Over heating protection
- Emergency Shut-Down

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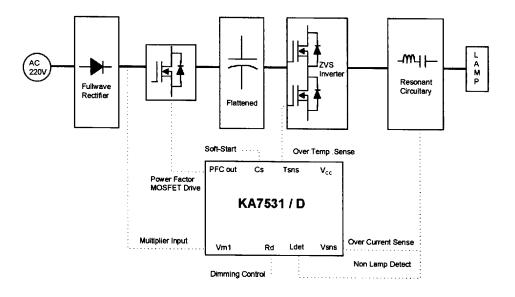
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2. SYSTEM BLOCK DIAGRAM (KA7531/D)



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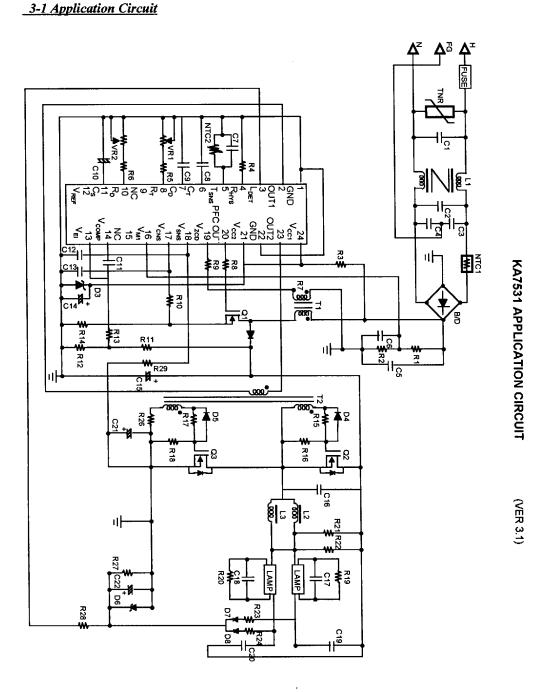
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KA7531 Industrial

3. APPLICATION CIRCUIT



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3-2 Parts List (APP-243)

ITEM	VALUE	ITEM	VALUE		ITEM	VALUE
R1	1.8 MΩ 1/2W	C1	0.1 µF	250V	TNR	12G471K
R2	10 kΩ 1/2W	C2	0.1 μ F	250V	NTC1	10D - 11
R3	100 kΩ 1/2W	C3	4700 pF	250V	NTC2	KTD5 - 350 (50k Ω)
R4	51 kΩ	C4	4700 pF	250V		
R5	33 kΩ	C5	563	600V	D1	1N4937
R6	120 kΩ	C6	103	40V	D2 - D4	1N4148
R7	27 Ω	C7	104	16V	D5 - D8	1N4937
R8	22 kΩ	C8	331	10V		
R9	330 Ω	C9	103	10V	ZD1	18V 1W
R10	150 kΩ	C10	10 µ F	16V		
R11	1 Ω 1W	C11	104	16V	Q1 - Q3	IRF830
R12	1 MΩ 1/2W	C12	10 µ F	16V		
R13	6.2 kΩ 1/2W	C13	332	10V	L1	BSF-2125
R14	60 kΩ	C14	47 μF	25V	L2, L3	E125
R15	51 Ω	C15	47 μF	450V	T1	El25
R16	51 Ω	C16	222	630V	T2	EE1619
R17	3.4 Ω	C17	562	1000V		
R18	300 kΩ	C18	562	1000V	B/D	KBL205
R19	390 kΩ	C19	103	630V	IC	KA7531
R20	390 kΩ	C20	103	630V		
R21	1 MΩ	C21	103	630V	FUSE	250V/2A
R22	1 MΩ	C22	103	630V		
R23	20 MΩ	C23	103	10V		
R26	2.2 ΜΩ					
R27	2.2 kΩ					
VR1	10 kΩ					
VR2	500 kΩ					

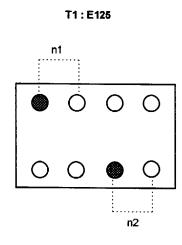
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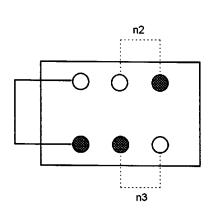
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3-3 Trans SPEC. (P.C.B TOP VIEW)

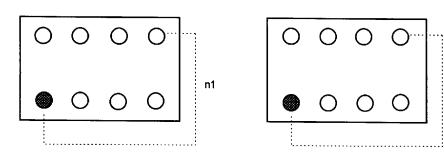




T2:EE125

L2 : E125

L3 : E125



ITEM	Φ	n1	n2	n3	n1 Value	Remark
T1	0.35	120 Turn	11 Turn	-	1.9 mH	
T2	0.25	32 Turn	24 Turn	24 Turn		
L2, L3	0.35	150 Turn	-	-	3.0 mH	

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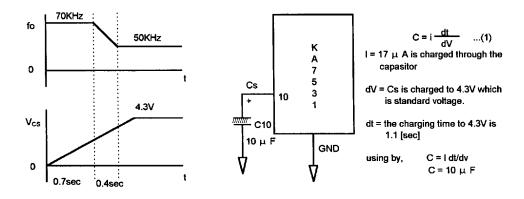
4. FUNCTION BLOCK DESCRIPTION

4 - 1 Start-up Operation

The KA7531 starts to operate when V_{CC} is more than start threshold voltage [10V], and operating current is 10mA. If the V_{CC} decreases less than UVLO (under voltage lock out) hysteresis width, IC's operation will stop. And then all the internal circuit begin to RESET, hold the stand-by state, At this time of this function operate, stand-by state current is about 0.9mA.

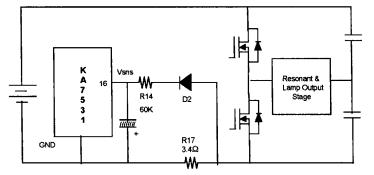
4 - 2 Soft - Stsrt

The 3 - step - soft - start function is pre-heat filament for 0.7 [sec] with a frequency that has a 20KHZ higher than normal control frequency of IC. And having high frequency (more than 20 KHZ) decreased to normal frequency linearly for about 0.4 [sec].



4 - 3 Over Current Protection

In this function, sensing a input and when input becomes over current state, the output of IC will be shut-down. So this system is designed to have a function like that.



If the voltage level of pin #16 becomes more than 3V, the output will be shut-down . In the normal state, After removal of overcurrent state, IC's output is on-state. To make output onstate, IC's intenal latch must be removed. To get above function, UVLO must be changed from off-state to on-state.

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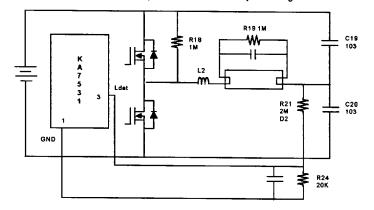
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4 -4 No Load Protection

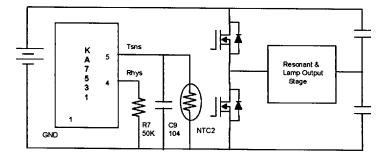
The KA7531 have a function sensing a 1 lamp insertion and a 2 lamp insertion or not. In case of no load, this system have protection circuit operated and IC's output shut down. When the insertion state change from 1 lamp to 2 lamp, lamp reset function restarting from 3-step soft start is operated. And also new inserted lamps strikes after filament pre-heating.



When the pin#3, of IC becomes lower than 1.4V, The output will be shut-down. In the state of lamp insertion, DC voltage is devided by R18, R19, R21, R23. DC link voltage in R23 is supplied to pin#3(Ldet) more than 1.4V

4 - 5 Over Temperature Protection

This function is designed to protect system by shut-down of IC's output. Using a NTC (negative temperature coefficient) this system sense a emitting heat state of power switching component when sensed temperature is more than specified temperature.



In this circuit, If the voltage level of pin#5 Tsns is less than 0.9V, IC's output is shut-down. Once the system is shut-down, This system is restarted with temperature hysteresis characteristics by voltage level of pin#4. This circuit is designed so that shut-down at the temperature of 90 $\[mathcar{C}\]$ and restart at 50 $\[mathcar{C}\]$. The NTC have a value of 50k $\[mathcar{\Omega}\]$ at the temperature of 25 $\[mathcar{C}\]$.

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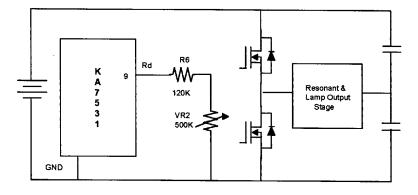
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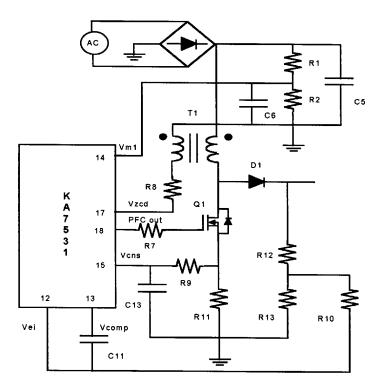


4 - 6 Dimming Control



Current flowing into Rd is contolled by adjusting VR2(500K). And this makes output frequency variable. In the end, dimming control is possible.

<u>4 - 7 P. F. C</u>



Refer to Power Device (95, 3nd Edition) of SANSUNG Data Book. (Page 73 - 86)

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5. FUNCTION COMPARISION TABLE (KA7521 / 7522 / 7531)

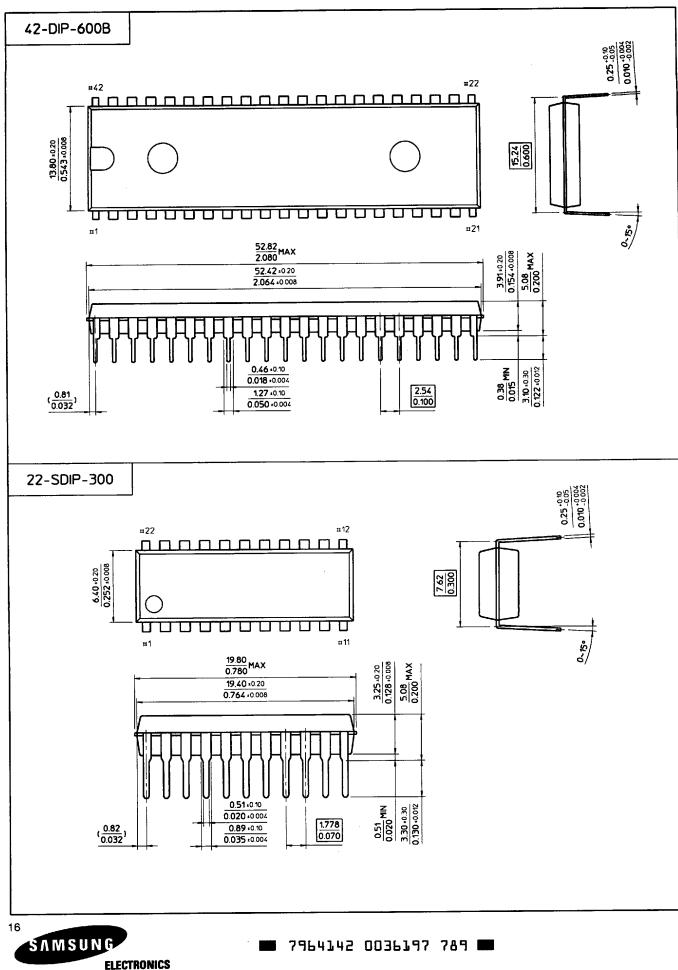
Parameter	KA7521	KA7522	KA7531	Remark
1. P. F. C	about 0.67	about 0.67	over 0.99	
2. Soft-Start Function	0	0	0	·
3. Input Voltage Variation Protection	AC 220V -20% +50%	AC 220V ± 50%	AC 220V ± 20%	
4. Over-Voltage Protection	0	0	0	· ······
5. Emergency System Protection	0	0	0	
6. Over-Heating Protection	0	0	0	
7. Non-lamp Dtection	0	0	0	
8. Dimming Control	100% ~ 10%	100% ~ 10%	100% ~ 10%	
9. AVS-Driving	0	0	0	
10. ZVS Guard Control	-	0	-	
11. Current Feedback Control	•	0	-	
12. Lamp reset	-	0	-	Preheating function while lamp selting on Power-on stage
13. Input limit & Brown out	-	0	-	
14. Low Temperature sense for preheating time control	-	0	-	

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